

ADVANCE INFORMATION

DS3608 - 2.0

SL531

250MHz TRUE LOG IF AMPLIFIER

The SL531 C is a wide band amplifier designed for use in logarithmic IF amplifiers of the true log type. The input and log output of a true log amplifier are at the same frequency i e detection does not occur. In successive detection log amplifiers (using SL521 SL1521 types) the log output is detected.

The small signal gain is 10dB and bandwidth is over 500MHz. At high signal levels the gain of a single stage dropstounity. A cascade of such stages give a close approximation to a log characteristic at centre frequencies between 10and 200MHz.

An important feature of the device is that the phase shift is nearly constant with signal level. Thus any phase information on the input signal is preserved through the strip.

The device is also available as the 5962-92084 which has guaranteed operation over the full Military Temperature Range and is screened to MIL-STD-883 Class B. Data is available separately

FEATURES

- Low Phase Shift vs Amplitude
- On-Chip Supply Decoupling
- Low External Components Count

APPLICATIONS

True Log Strips with:-

Log Range 70dB

■ Centre frequencies 10 - 200MHz

■ Phase Shift ± 0.5 degrees / 10dB

ABSOLUTE MAXIMUM RATINGS

(Non-simultaneous)

Supply voltage +12 volts
Storage temperature range -65°C to +150°C

Operating temperature range -55°C to +125°C

See operating notes

Max junction temperature 175°C

Junction - ambient thermal resistance 220°C/Watt

Junction - case thermal resistance 80°C/Watt

CIRCUIT DESCRIPTION

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The SL531 transfer characteristic has two regions For small input signals it has a nominal gain of 10 dB. at large signals the gain falls to unity (see Fig 7) This is achieved by operating a limiting amplifier and a unity gain amplifier in parallel (see Fig 3) Tr1 and Tr4 comprise the long tailed pair limiting amplifier, the tail current being supplied byTrS, see Fig 2 Tr2 and Tr3 form the unity gain amplifier the gain of which is defined by the emitter resistors The outputs of both stages are summed in the 300 ohm resistor and Tr7 acts as an emitter follower output buffer. Important features are the amplitude and phase linearity of the unity gain stage which is achieved by the use of 5 GHz transistors with carefully optimised geometries.

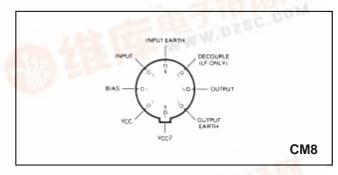


Fig.1 Pin connections

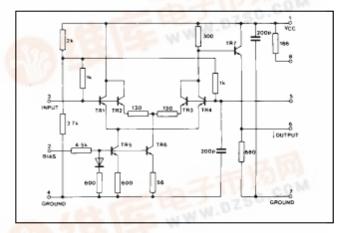


Fig.2 Circuit diagram

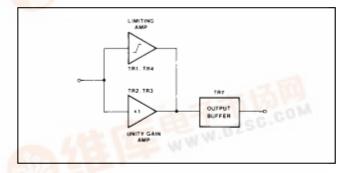


Fig.3 Block diagram

ORDERING INFORMATION

5962-92084 (SMD) SL531 C CM

ELECTRICAL CHARACTERISTICS

These characteristics are guaranteed over the following conditions (unless otherwise stated)

Test circuit Fig (4)
Frequency 60MHz
Supply voltage 9 volts
Ambient temperature 22±2°C

Characteristic		Value		Units	Conditions
	Min.	Тур.	Max.		
Small signal voltage gain High level slope gain Upper cut off frequency Lower cut off frequency Supply current	8 -1 250	10 0 500 3 17	12 +1 10 25	dB dB MHz MHz mA	Vin = -30dBm -3dB w.r.t. ± 60MHz
Phase change with input amplitude Input impedance Output impedance			3 vith 1kΩ th 25nH		-Vin = 30dBm to +10dBm f = 10 - 200MHz

OPERATING NOTES

1. Supply Voltage Options

An on chip resistor is provided which can be used to drop the supply voltage instead of the external 180 ohms shown in the test circuit. The extra dissipation in this resistor reduces the maximum ambient operating temperature to 100°C. It is also possible to use a 6 volt supply connected directly to pins 1 and 2 Problems with feedback on the supply line etc may occur in this connection and RF chokes may be required in the supply line between stages.

2. Layout P recautions

The internal decoupling capacitors help prevent high frequency instability however normal high frequency layout precautions are still necessary. Coupling capacitors should be physically small and be connected with short leads. It is most important that the ground connections are made with short leads to a continuous ground plane.

3. Low Frequency Response

The LF response is determined by the on chip capacitors. It can be extended by extra external decoupling on pins 5 and 1.

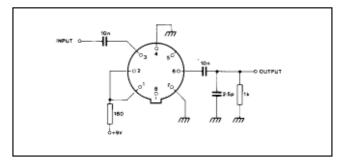


Fig.4 Test ciruit

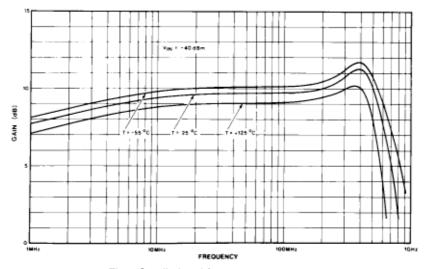


Fig.5 Small signal frequency response

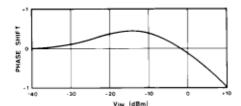


Fig.6 Phase v. input

TYPICAL APPLICATION—6 STAGE LOG STIP

Input log range OdBm to—70dBm Low level gain 60dB (—70dBm in) Output dynamic range 20dB Phase shift (over log range) ±3° Frequency range 10—200MHz

The circuit shown in Fig 9 is designed to illustrate the use of the SL531 in a complete strip The supply voltage is fed to each stage via an external 180Ω resistor to allow operation to $125^{\circ}C$ ambient If the ambient can be limited to +100°C then the internal resistor can be used to reduce the external component count Interstage coupling is very simple with just a capacitor to isolate bias levels being necessary. No connection is necessary to pin 5 unless operation below 10MHz is required. It is important to provide extra decoupling on pin 1 of the first stage to prevent positive feedback occuring down the supply line. An SL560 is used as a unity gain buffer the output of the log strip being attenuated before the SL560 to give a nominal 0dBm output into 50Ω .

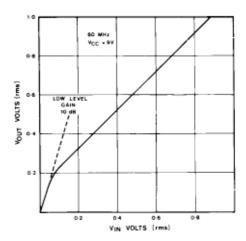


Fig.7 Transfer characteristics linear plot

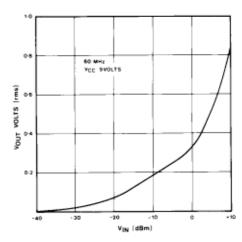


Fig.8 Transfer characteristics logarithmic input scale

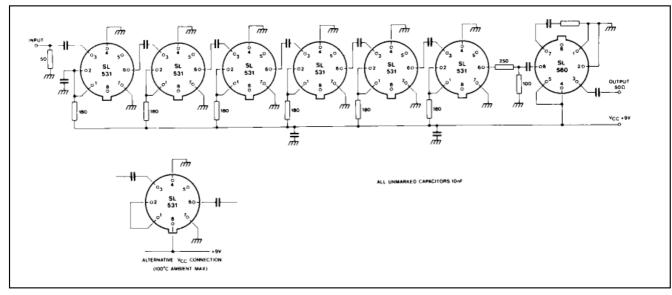


Fig.9 Circuit diagram 6 stage strip



HEADQUARTERS OPERATIONS

GEC PLESSEY SEMICONDUCTORS

Cheney Manor, Swindon,

Wiltshire SN2 2QW, United Kingdom.

Tel: (0793) 518000 Fax: (0793) 518411

GEC PLESSEY SEMICONDUCTORS

P.O. Box 660017 1500 Green Hills Road. Scotts Valley, California 95067-0017, United States of America. Tel: (408) 438 2900

Fax: (408) 438 5576

CUSTOMER SERVICE CENTRES

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- JAPAN Tokyo Tel: (03) 5276-5501 Fax: (03) 5276-5510 NORTH AMERICA Scotts Valley, USA Tel (408) 438 2900 Fax: (408) 438 7023.
- SOUTH EAST ASIA Singapore Tel: (65) 3827708 Fax: (65) 3828872
- SWEDEN Stockholm, Tel: 46 8 702 97 70 Fax: 46 8 640 47 36
- UK, EIRE, DENMARK, FINLAND & NORWAY Swindon Tel: (0793) 518510 Fax: (0793) 518582

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